

(SMALL-SIGNAL TRANSISTOR)

2SA1287

FOR RELAY DRIVE, POWER SUPPLY APPLICATION
SILICON PNP EPITAXIAL TYPE

DESCRIPTION

2SA1287 is silicon PNP epitaxial type transistor. Designed with high Voltage, high collector current, dissipation and high hFE.
Complementary with 2SC3247.

FEATURE

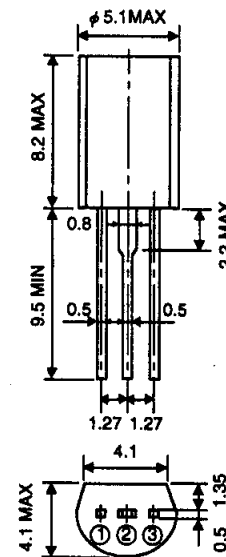
- High hFE hFE=400 to 800
- High voltage V_{CEO}=-50V
- Low collector to emitter saturation voltage.
V_{CE(sat)}=-0.2V (@I_C=-500mA, I_B=-10mA)
- High collector dissipation P_C=900mW

APPLICATION

Relay drive or power supply of audio machine, VCR, and other electronic machine.

OUTLINE DRAWING

Unit:mm



TERMINAL CONNECTOR

- ① : EMITTER EIAJ: -- JEDEC: --
- ② : COLLECTOR
- ③ : BASE

Note)
The dimension without tolerance represent central value.

MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit
V _{CB0}	Collector to Base voltage	-50	V
V _{EB0}	Emitter to Base voltage	-6	V
V _{CEO}	Collector to Emitter voltage	-50	V
I _{CM}	Peak collector current	-2	A
I _C	Collector current	-1	A
P _C	Collector dissipation(Ta=25°C)	900	mW
T _J	Junction temperature	+150	°C
T _{stg}	Storage temperature	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C)

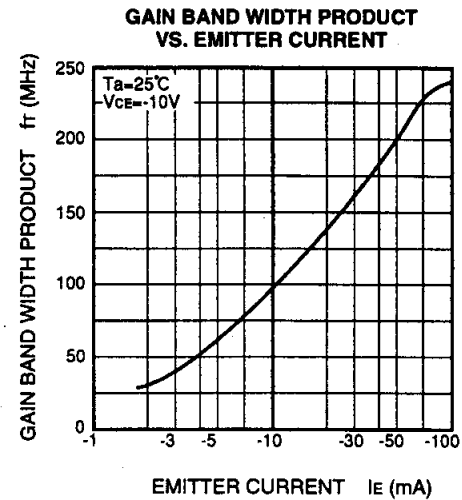
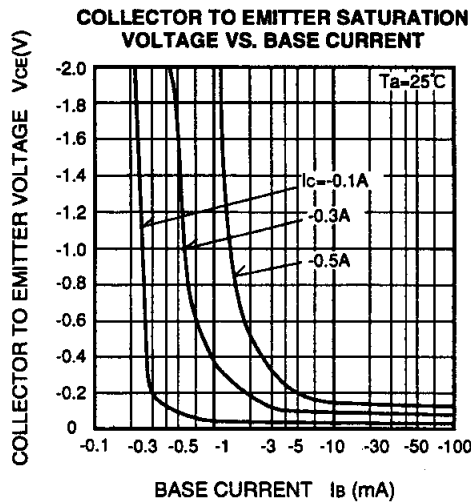
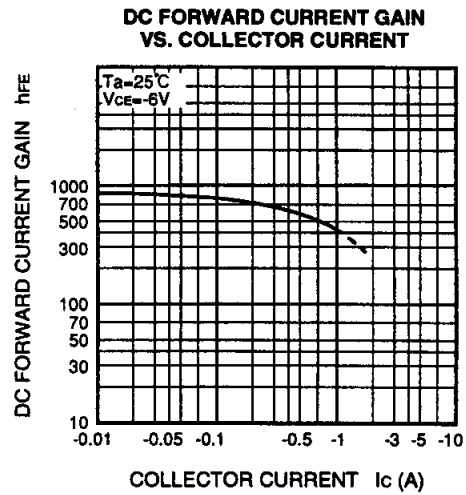
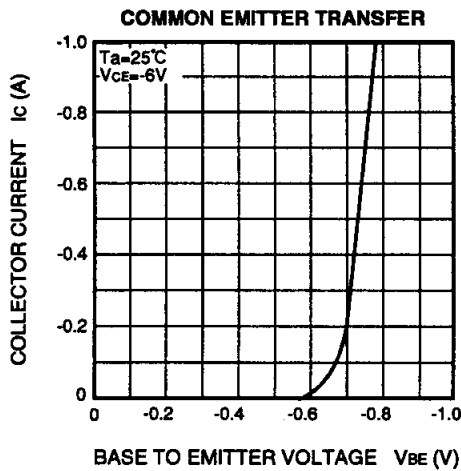
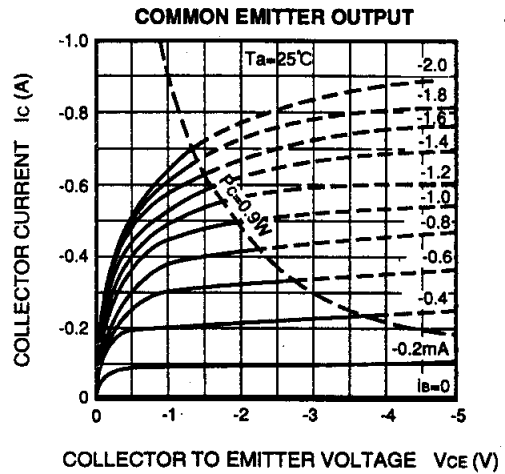
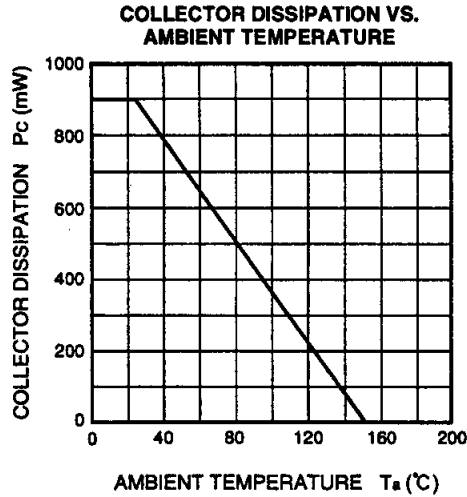
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V _{(BR)CBO}	C to B break down voltage	I _C =-10 μA, I _E =0	-50			V
V _{(BR)EBO}	E to B break down voltage	I _E =-10 μA, I _C =0	-6			V
V _{(BR)CEO}	C to E break down voltage	I _C =-1mA, R _{BE} =∞	-50			V
I _{CBO}	Collector cut off current	V _{CB} =-40V, I _E =0			-0.1	μA
I _{EBO}	Emitter cut off current	V _{EB} =-2V, I _C =0			-0.1	μA
hFE *	DC forward current gain	V _{CE} =-6V, I _C =-100mA	400		800	—
V _{CE(sat)}	C to E saturation voltage	I _C =-500mA, I _B =-10mA		-0.2	-0.5	V
f _T	Gain band width product	V _{CE} =-10V, I _E =10mA		90		MHz
C _{ob}	Collector output capacitance	V _{CB} =-10V, I _E =0, f=1MHz		30		pF

* : It shows hFE classification in right table.

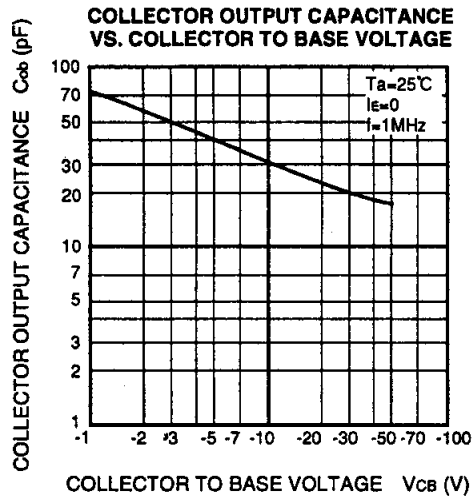
Item	G
hFE	400 to 800

ISAHAYA ELECTRONICS CORPORATION

TYPICAL CHARACTERISTICS



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SILICON PNP EPITAXIAL TYPE



 **ISAHAYA ELECTRONICS CORPORATION**

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